

LT050MS/LT050PS

■ Features

- (1) Maximum optical power output : 5mW
- (2) Wavelength : 635nm band
- (3) Compact φ5.6mm package
- (4) Stable transverse mode
- (5) High temperature operation at 60°C
- (6) Realizes high temperature operation by introducing a tensil strain into the multi-quantum well active layer
- (7) Stable optical characteristics by developing an index guide structure of MBE 2-times growth

■ Model No.

- (1) LT050MS … Dual power supply
- (2) LT050PS … Single power supply

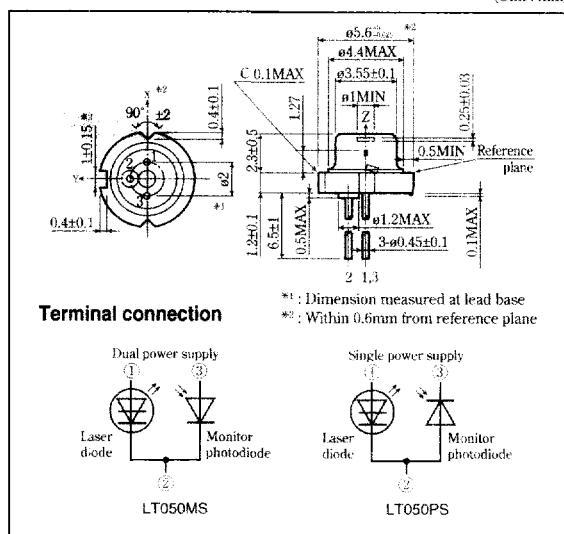
■ Applications

- (1) Bar code readers, Pointers etc,

Compact Size Laser Diode for Pointers(635nm-5mW)

■ Outline Dimensions

(Unit : mm)



■ Absolute Maximum Ratings

(Tc=25°C)

Parameter	Symbol	Rating	Unit
Optical power output	P _O	5	mW
Reverse voltage	V _R	2	V
Monitor photodiode		30	V
* ¹ Operating temperature	T _{opr}	-10 to +60	°C
* ¹ Storage temperature	T _{stg}	-40 to +85	°C
* ² Soldering temperature	T _{sld}	260°C/5s	-

^{*1} Case temperature^{*2} At the position of 1.6mm or more from the lead base

■ Electro-optical Characteristics*¹

(Tc=25°C)

Parameter		Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Threshold current		I _{th}	-		-	50	65	mA
Operating current		I _{op}	Po=3mW		-	60	75	mA
Operating voltage		V _{op}	Po=3mW		-	2.3	2.7	V
* ² Wavelength		λ _p	Po=3mW		630	635	640	nm
Monitor current		I _m	Po=3mW, V _R =5V	LT050MS	-	200	-	μA
				LT050PS	-	80	-	μA
Radiation characteristics	* ³ Angle	Parallel to junction	θ//	Po=3mW	7.0	8.5	10.0	°
		Perpendicular to junction	θ⊥	Po=3mW	25.0	30.0	35.0	°
Ripple		-	Po=3mW	-	-	±20	-	%
Emission point accuracy	Angle	Δθ//	Po=3mW	-	-	±2	-	°
		Δθ⊥	Po=3mW	-	-	±3	-	°
	Position	Δx,Δy,Δz	-	-	-	±80	-	μm
Differential efficiency		η	2mW I (3mW) - I (1mW)		0.25	0.35	0.60	mW/mA

*¹ Initial value, CW (Continuous Wave) drive*² Oscillation mode, single transverse mode*³ Angle at 50% peak intensity (full-width at half-maximum)■ Electrical Characteristics of Photodiode
(LT050MS)

(Tc=25°C)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Dark current	I _d	V _R =5V		-	-	150	nA

(LT050PS)

(Tc=25°C)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Dark current	I _d	V _R =5V		-	-	150	nA

• Please refer to the chapter "Handling Precautions".